4-Bit Dual-Supply Inverting Level Translator

The NLSV4T240 is a 4-bit configurable dual-supply voltage level translator. The input A_n and output B_n ports are designed to track two different power supply rails, V_{CCA} and V_{CCB} respectively. Both supply rails are configurable from 0.9 V to 4.5 V allowing universal low-voltage translation from the input A_n to the output B_n port.

Features

- Wide V_{CCA} and V_{CCB} Operating Range: 0.9 V to 4.5 V
- High-Speed w/ Balanced Propagation Delay
- Inputs and Outputs have OVT Protection to 4.5 V
- Non-preferential V_{CCA} and V_{CCB} Sequencing
- Outputs at 3-State until Active V_{CC} is Reached
- Power-Off Protection
- Outputs Switch to 3-State with V_{CCB} at GND
- Ultra-Small Packaging: 1.7 mm x 2.0 mm UQFN12
- This is a Pb-Free Device

Typical Applications

• Mobile Phones, PDAs, Other Portable Devices

Important Information

• ESD Protection for All Pins: HBM (Human Body Model) > 6000 V

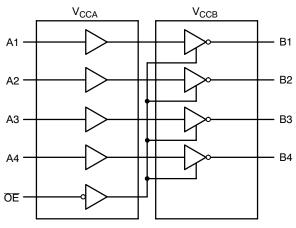
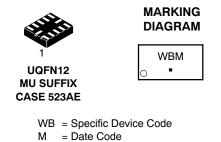


Figure 1. Logic Diagram

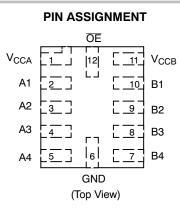


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= Pb-Free Package



ORDERING INFORMATION

Device	Package	Shipping [†]
NLSV4T240MUTAG	UQFN12 (Pb-Free)	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

PIN ASSIGNMENT

PIN	FUNCTION
V _{CCA}	Input Port DC Power Supply
V _{CCB}	Output Port DC Power Supply
GND	Ground
A _n	Input Port
B _n	Output Port
ŌĒ	Output Enable

TRUTH TABLE

In	Inputs					
OE	A _n	B _n				
L	L	н				
L	н	L				
н	х	3-State				

MAXIMUM RATINGS

Symbol	Rating		Value	Condition	Unit
V_{CCA}, V_{CCB}	DC Supply Voltage		-0.5 to +5.5		V
VI	DC Input Voltage	A _n	-0.5 to +5.5		V
V _C	Control Input	ŌĒ	-0.5 to +5.5		V
Vo	DC Output Voltage (Power Down)	B _n	-0.5 to +5.5	$V_{CCA} = V_{CCB} = 0$	V
	(Active Mode)	B _n	-0.5 to +5.5		V
	(Tri-State Mode)	B _n	-0.5 to +5.5		V
I _{IK}	DC Input Diode Current		-20	V _I < GND	mA
I _{OK}	DC Output Diode Current		-50	V _O < GND	mA
Ι _Ο	DC Output Source/Sink Current		±50		mA
I _{CCA} , I _{CCB}	DC Supply Current Per Supply Pin		±100		mA
I _{GND}	DC Ground Current per Ground Pin		±100		mA
T _{STG}	Storage Temperature		-65 to +150		°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V_{CCA}, V_{CCB}	Positive DC Supply Voltage		0.9	4.5	V
VI	Bus Input Voltage		GND	4.5	V
V _C	Control Input	ŌĒ	GND	4.5	V
V _{IO}	Bus Output Voltage (Power Down Mode)	Bn	GND	4.5	V
	(Active Mode)	B _n	GND	V _{CCB}	V
	(Tri-State Mode)	B _n	GND	4.5	V
T _A	Operating Temperature Range		-40	+85	°C
$\Delta t / \Delta V$	Input Transition Rise or Rate V _I , from 30% to 70% of V _{CC} ; V _{CC} = 3.3 V ± 0.3 V		0	10	nS

DC ELECTRICAL CHARACTERISTICS

					-40°C t	o +85°C	
Symbol	Parameter	Test Conditions	V _{CCA} (V)	V _{CCB} (V)	Min	Max	Unit
V _{IH}	Input HIGH Voltage		3.6 - 4.5	0.9 - 4.5	2.2	-	V
	(An, OE)		2.7 – 3.6		2.0	-	
			2.3 – 2.7		1.6	-	
			1.4 - 2.3		0.65 * V _{CCA}	-	
			0.9 – 1.4		0.9 * V _{CCA}	-	
V _{IL}	Input LOW Voltage		3.6 - 4.5	0.9 - 4.5	-	0.8	V
	(An, OE)		2.7 – 3.6	1	-	0.8	
			2.3 – 2.7		-	0.7	
			1.4 - 2.3	1	-	0.35 * V _{CCA}	
			0.9 – 1.4	1	-	0.1 * V _{CCA}	
V _{OH}	Output HIGH Voltage	I_{OH} = -100 µA; V _I = V _{IH}	0.9 - 4.5	0.9 - 4.5	$V_{CCB} - 0.2$	-	V
		I _{OH} = -0.5 mA; V _I = V _{IH}	0.9	0.9	0.75 * V _{CCB}	-	
		$I_{OH} = -2 \text{ mA}; V_I = V_{IH}$	1.4	1.4	1.05	-	
		$I_{OH} = -6 \text{ mA}; V_I = V_{IH}$	1.65	1.65	1.25	-	
			2.3	2.3	2.0	-	
		I _{OH} = -12 mA; V _I = V _{IH}	2.3	2.3	1.8	-	
			2.7	2.7	2.2	-	
		I _{OH} = -18 mA; V _I = V _{IH}	2.3	2.3	1.7	-	
			3.0	3.0	2.4	-	
		$I_{OH} = -24 \text{ mA}; V_I = V_{IH}$	3.0	3.0	2.2	-	
V _{OL}	Output LOW Voltage	I_{OL} = 100 μ A; V _I = V _{IL}	0.9 - 4.5	0.9-4.5	-	0.2	V
		I_{OL} = 0.5 mA; V_I = V_{IH}	1.1	1.1	-	0.3	
		$I_{OL} = 2 \text{ mA}; V_I = V_{IH}$	1.4	1.4	-	0.35	
		$I_{OL} = 6 \text{ mA}; V_I = V_{IL}$	1.65	1.65	-	0.3	
		I _{OL} = 12 mA; V _I = V _{IL}	2.3	2.3	-	0.4	
			2.7	2.7	-	0.4	
		I _{OL} = 18 mA; V _I = V _{IL}	2.3	2.3	-	0.6	
			3.0	3.0	-	0.4	
		I _{OL} = 24 mA; V _I = V _{IL}	3.0	3.0	-	0.55	
I	Input Leakage Current	$V_I = V_{CCA}$ or GND	0.9 - 4.5	0.9 - 4.5	-1.0	1.0	μA
I _{OFF}	Power-Off Leakage Current	<u>OE</u> = 0 V	0 0.9 – 4.5	0.9 – 4.5 0	-1.0 -1.0	1.0 1.0	μA
I _{CCA}	Quiescent Supply Current		0.9 - 4.5	0.9 - 4.5	-	2.0	μA
I _{CCB}	Quiescent Supply Current		0.9 – 4.5	0.9 - 4.5	-	2.0	μA
CCA + ICCB	Quiescent Supply Current		0.9 – 4.5	0.9 – 4.5	-	4.0	μA
ΔI_{CCA}	Increase in I_{CC} per Input Voltage, Other Inputs at V_{CCA} or GND	$V_{I} = V_{CCA} - 0.6 V;$ $V_{I} = V_{CCA}$ or GND	4.5 3.6	4.5 3.6	-	10 5.0	μA
ΔI_{CCB}	Increase in I_{CC} per Input Voltage, Other Inputs at V_{CCA} or GND	$V_{I} = V_{CCA} - 0.6 V;$ $V_{I} = V_{CCA}$ or GND	4.5 3.6	4.5 3.6	-	10 5.0	μA
I _{OZ}	I/O Tri-State Output Leakage Current	$T_A = 25^{\circ}C, \overline{OE} = 0 V$	0.9 – 4.5	0.9 – 4.5	-1.0	1.0	μA

TOTAL STATIC POWER CONSUMPTION (I_{CCA} + I_{CCB})

					–40°C t	o +85°C					
	V _{CCB} (V)										
4.5 3.3 2		2.8 1.8		.8	0.9		1				
V _{CCA} (V)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
4.5		2		2		2		2		< 1.5	μA
3.3		2		2		2		2		< 1.5	μA
2.8		< 2		< 1		< 1		< 0.5		< 0.5	μA
1.8		< 1		< 1		< 0.5		< 0.5		< 0.5	μA
0.9		< 0.5		< 0.5		< 0.5		< 0.5		< 0.5	μA

NOTE: Connect ground before applying supply voltage V_{CCA} or V_{CCB}. This device is designed with the feature that the power-up sequence of V_{CCA} and V_{CCB} will not damage the IC.

AC ELECTRICAL CHARACTERISTICS

							–40°C t	o +85°C					
							Vcc	_в (V)					
			4	.5	3	.3	2	.8	1	.8	1	.2	
Symbol	Parameter	V _{CCA} (V)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
t _{PLH} ,	Propagation	4.5		1.6		1.8		2.0		2.1		2.3	nS
t _{PHL} (Note 1)	Delay,	3.3		1.7		1.9		2.1		2.3		2.6	
	A _n to B _n	2.8		1.9		2.1		2.3		2.5		2.8	
		1.8		2.1		2.4		2.5		2.7		3.0	
		1.2		2.4		2.7		2.8		3.0		3.3	
t _{PZH} ,	Output	4.5		2.6		3.8		4.0		4.1		4.3	nS
t _{PZL} (Note 1)	Enable, OE to B _n	3.3		3.7		3.9		4.1		4.3		4.6	
(NOLE I)		2.5		3.9		4.1		4.3		4.5		4.8	1
		1.8		4.1		4.4		4.5		4.7		5.0	
		1.2		4.4		4.7		4.8		5.0		5.3	
t _{PHZ} ,	Output	4.5		2.6		3.8		4.0		4.1		4.3	nS
t _{PLZ} (Note 1)	Disable,	3.3		3.7		3.9		4.1		4.3		4.6	
(NOLE I)	OE to B _n	2.5		3.9		4.1		4.3		4.5		4.8	
		1.8		4.1		4.4		4.5		4.7		5.0	
		1.2		4.4		4.7		4.8		5.0		5.3	
t _{OSHL} ,	Output to	4.5		0.15		0.15		0.15		0.15		0.15	nS
t _{OSLH} (Note 1)	Output Skew,	3.3		0.15		0.15		0.15		0.15		0.15	
	Time	2.5		0.15		0.15		0.15		0.15		0.15	
		1.8		0.15		0.15		0.15		0.15		0.15	
		1.2		0.15		0.15		0.15		0.15		0.15	

1. Propagation delays defined per Figure 2.

CAPACITANCE

Symbol	Parameter	Test Conditions	Typ (Note 2)	Unit
C _{IN}	Control Pin Input Capacitance	V_{CCA} = V_{CCB} = 3.3 V, V_{I} = 0 V or $V_{CCA/B}$	3.5	pF
C _{I/O}	I/O Pin Input Capacitance	V_{CCA} = V_{CCB} = 3.3 V, V_{I} = 0 V or $V_{CCA/B}$	5.0	pF
C _{PD}	Power Dissipation Capacitance	V_{CCA} = V_{CCB} = 3.3 V, V_{I} = 0 V or V_{CCA},f = 10 MHz	20	pF

2. Typical values are at $T_A = +25^{\circ}$ C. 3. C_{PD} is defined as the value of the IC's equivalent capacitance from which the operating current can be calculated from: $I_{CC(operating)} \cong C_{PD} \times V_{CC} \times f_{IN} \times N_{SW}$ where $I_{CC} = I_{CCA} + I_{CCB}$ and N_{SW} = total number of outputs switching.

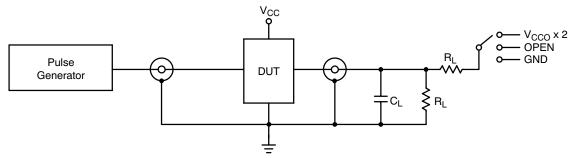
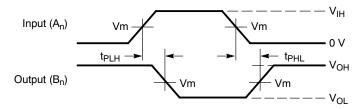
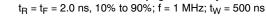


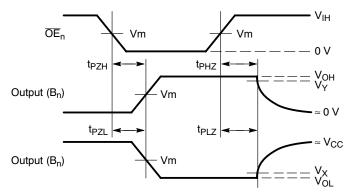
Figure 2. AC (Propagation Delay) Test Circuit

Test	Switch
t _{PLH} , t _{PHL}	OPEN
t _{PLZ} , t _{PZL}	V _{CCO} x 2
t _{PHZ} , t _{PZH}	GND
C_L = 15 pF or equivalent (include R _L = 2 k Ω or equivalent Z _{OUT} of pulse generator = 50 Ω	es probe and jig capacitance)



Waveform 1 – Propagation Delays



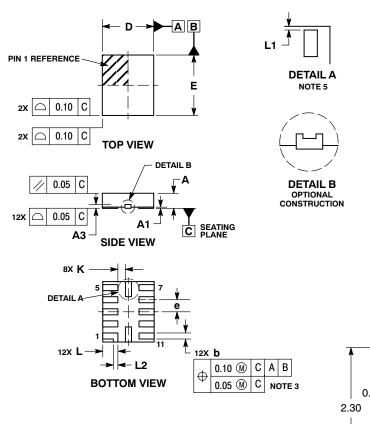


Waveform 2 – Output Enable and Disable Times t_R = t_F = 2.0 ns, 10% to 90%; f = 1 MHz; t_W = 500 ns

	V _{CC}										
Symbol	3.0 V – 4.5 V	2.3 V – 2.7 V	1.65 V – 1.95 V	1.4 V – 1.6 V	0.9 V – 1.3 V						
V _{mA}	V _{CCA} /2										
V _{mB}	V _{CCB} /2										
V _X	V _{OL} x 0.1										
V _Y	V _{OH} x 0.9										

PACKAGE DIMENSIONS

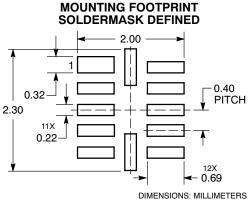
UQFN12 1.7x2.0, 0.4P CASE 523AE-01 ISSUE A



NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME V14 5M 1994

- Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS 3. DIMENSION & APPLIES TO PLATED TERMINAL
- 3. DIMENSION 5 APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 MM FROM TERMINAL TIP.
- A. MOLD FLASH ALLOWED ON TERMINALS
 ALONG EDGE OF PACKAGE. FLASH 0.03
 MAX ON BOTTOM SURFACE OF
 TERMINALS.
 5. DETAIL A SHOWS OPTIONAL
- 5. DETAIL A SHOWS OPTIONAL CONSTRUCTION FOR TERMINALS.

	MILLIMETERS	
DIM	MIN	MAX
Α	0.45	0.55
A1	0.00	0.05
A3	0.127 REF	
b	0.15	0.25
D	1.70 BSC	
Е	2.00 BSC	
е	0.40 BSC	
K	0.20	
L	0.45	0.55
L1	0.00	0.03
L2	0.15 REF	



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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